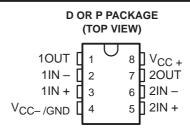
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- Wide Range of Supply Voltages
 Single Supply . . . 5 V to 30 V
 Dual Supplies . . . ± 2.5 V to ± 15 V
- Class AB Output Stage
- True Differential Input Stage
- Low Input Bias Current
- Internal Frequency Compensation
- Short-Circuit Protection

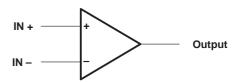
description

The TL322C and the TL322I are dual operational amplifiers similar in performance to the uA741 but with several distinct advantages. They are designed to operate from a single supply over a range of voltages from 5 V to 30 V. Operation from split supplies is also possible provided the difference between the two supplies is 5 V to 30 V. The common-mode input range includes the negative supply. Output range is from the negative supply to $V_{\rm CC}$ –1.5 V. Quiescent supply currents per amplifier are typically less than one-half those of the uA741.

The TL322C is characterized for operation from 0°C to 70°C. The TL322I is characterized for operation from -40°C to 85°C.



symbol (each amplifier)

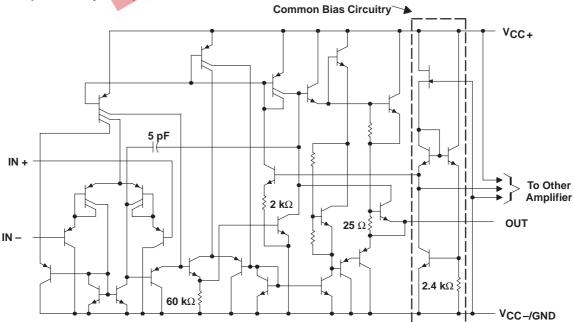


AVAILABLE OPTIONS

al al	2 /5	PACKAGE					
TA	V _{IO} MAX AT 25°C	SMALL OUTLINE (D)	PLASTIC DIP (P)				
0°C to 70°c	10 mV	TL322CD	TL322CP				
0°C to 70°c	8 mV	TL322ID	TL322IP				

D packages are available taped and reeled. Add R suffix to device type, (e.g., TL322CDR).

schematic (each amplifier)



All component values shown are nominal.

Texas VI

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

	TL322C	TL322I	UNIT		
Supply voltage V _{CC+} (see Note 1)	18	18	V		
Supply voltage V _{CC} (see Note 1)	-18	-18	V		
Supply voltage V _{CC+} (with respect to V _{CC-})	36	36	V		
Differential input voltage (see Note 2)	±36	±36	V		
Input voltage (see Notes 1 and 3)	±18	±18	V		
Continuous total power disspation	See Dissi	See Dissipation Rating Table			
Operating free-air temperature range	0 to 70	-40 to 85	°C		
Storage temperature range	-65 to 150	-65 to 150	°C		
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260	260	°C		

- NOTES: 1. These voltage values are with respect to the midpoint between V_{CC+} and V_{CC-} .
 - 2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.
 - 3. Neither input must ever be more positive than V_{CC+} or more negative than V_{CC-} .

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{\scriptsize A}} \leq 25^{\circ}\mbox{\scriptsize C}$ POWER RATING	DERATING FACTOR	DERATE ABOVE T _A	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
D	680 mW	5.8 mW/°C	33°C	464 mW	377 mW
Р	680 mW	8.0 mW/°C	65°C	640 mW	520 mW

recommended operating conditions

	-				_
		6	MIN	NOM MAX	UNIT
Single supply voltage, V _{CC}	4 /		5	30	V
Dual supply voltage, V _{CC+}			2.5	15	V
Dual supply voltage, V _{CC} _			- 2.5	– 15	V



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electrical characteristics at specified free-air temperature, $V_{CC\pm}$ = 15 V (unless otherwise noted)

PARAMETER TEST CONDITION		TIONET	TL TL				TL322I		UNIT	
	PARAMETER	1EST CONDI	IIONSI	MIN	TYP	MAX	MIN	TYP	MAX	UNII
VIO	Input offset voltage	$V_{O} = 0,$	25°C		2	10		2	8	mV
V10	Input onoct voltage	$R_S = 50 \Omega$	Full range			12			10	111.0
ανιο	Temperature coefficient of input offset voltage	$V_O = 0$, $R_S = 50 \Omega$	25°C		10			10		μV/°C
lio	Input offset current	VO = 0	25°C		30	50		30	75	nA
10	input onset current	VO = 0	Full range			200			250	11/4
αΙΙΟ	Temperature coefficient of input offset current	V _O = 0	25°C		50			50		pA/°C
lin.	Input bias current	V _O = 0	25°C		-0.2	-0.5		-0.2	-0.5	μА
ΙΒ	input bias current	vO = 0	Full range			-0.8			-1	μΑ
	Common-mode input			VCC-	$^{VCC-}$		VCC-	VCC-		
VICR	voltage range [‡]		25°C	to	to		to	to		V
				13	13.5		13	13.5		
		$R_L = 10 \text{ k}\Omega$	25°C	±12	±13.5	3	±12	±12.5		
Vом	Peak output voltage swing	R _L = 2 kΩ	25°C	±10	±13		±10	±12		V
			Full range	±10	34	4	±10			
_	Large-signal differential	$V_0 = \pm 10 \text{ V},$	25°C	20	200		20	200		
AVD	voltage amplification	$R_L = 2 k\Omega$	Full range	15	W.		15			V/mV
ВОМ	Maximum-output- swing bandwidth	$V_{O(PP)} = 20 \text{ V},$ $A_{VD} = 1,$ $THD \le 5\%,$ $R_{L} = 2 \text{ k}\Omega$	25°C	,CO	9			9		kHz
B ₁	Unity-gain bandwidth	$V_O = 50 \text{ mV},$ $R_L = 10 \text{ k}\Omega$	25°C		1			1		MHz
φm	Phase margin	$R_L = 2 k\Omega$, $C_L = 200 pF$	25°C		60°			60°		
rį	Input resistance	f = 20 Hz	25°C	0.3	1		0.3	1		МΩ
r _o	Output resistance	f = 20 Hz	25°C		75			75		Ω
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR} \text{ min},$ $R_S = 50 \Omega$	25°C	70	90		70	90		dB
ksvs	Supply voltage sensitivity $(\Delta V_{IO}/\Delta V_{CC})$	$V_{CC} = \pm 2.5 \text{ V to}$ $\pm 15 \text{ V},$ $R_S = 50 \Omega$	25°C		30	150		30	150	μV/V
los	Short-circuit output current§	V _O = 0	25°C	±10	±30	±45	±10	±30	±45	mA
Icc	Total supply current	V _O = 0, No load	25°C		1.4	4		1.4	4	mA

[†] All characteristics are under open-loop conditions unless otherwise noted. Full range for T_A is 0°C to 70°C for TL322C and -40°C to 85°C for TL322I.



[‡] The V_{ICR} limits are directly linked volt-for-volt to supply voltage; the positive limit is 2 V less than V_{CC+}.

[§] Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

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electrical characteristics, V_{CC+} = 5 V, V_{CC-} = 0 V, T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS†	TL322C			TL322I			UNIT
		TEST CONDITIONS!	MIN	TYP	MAX	MIN	TYP	MAX	UNII
VIO	Input offset voltage	$V_0 = 2.5 \text{ V}, R_S = 50 \Omega$		2	10			8	mV
IIO	Input offset current	V _O = 2.5 V		30	50			75	nA
I _{IB}	Input bias current			-0.2	-0.5			-0.5	pА
	Peak output voltage swing [‡]	$R_L = 10 \text{ k}\Omega$	3.3	3.5		3.3	3.5		
VOM		$R_L = 10 \text{ k}\Omega$,	V _{CC+} -1.7			V 47			V
		V _{CC+} = 5 V to 30 V				V _{CC+} -1.7	1.7		
	Large-signal differential	$V_0 = 1.7 \text{ V to } 3.3 \text{ V},$	00	000		20	200		V/mV
AVD	voltage amplification	$R_L = 2 k\Omega$	20	200					
ksvs	Supply voltage sensitivity $(\Delta V_{IO}/\Delta V_{CC+})$	V _{CC} = ±2.5 V to ±15 V			150			150	μV/V
Icc	Supply current	V _O = 2.5 V, No load		1.2	4		1.2	4	mA
V ₀₁ /V ₀₂	Crosstalk attenuation	A _{VD} = 100, f = 1 kHz to 20 kHz		120			120		dB

 $[\]ensuremath{^{\dagger}}\xspace$ All characteristics are specified under open-loop conditions.

i All characteristics are specified under open-loop conditions. ‡ Output will swing essentially to ground. switching characteristics, V_{CC+} = 15 V, V_{CC-} = -15 V A_{VD} = 1, T_A = 25°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN TYP MAX	UNIT
SR	Slew rate at unity gain	$V_I = \pm 10 \text{ V}$, $C_L = 100 \text{ pF}$, See Figure 1	0.6	V/μs
t _r	Rise time	50 TV 0 400 F D 4010	0.35	μs
t _f	Fall time	$\Delta V_{O} = 50$ mV, $C_{L} = 100$ pF, $R_{L} = 10$ k Ω , See Figure 1	0.35	μs
	Overshoot factor	Gee rigule 1	20%	
	Crossover distortion	$V_{I(PP)} = 30 \text{ mV}, V_{O(PP)} = 2 \text{ V}, f = 10 \text{ kHz}$	1%	

PARAMETER MEASUREMENT INFORMATION

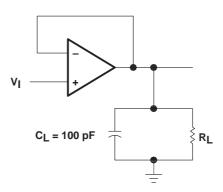


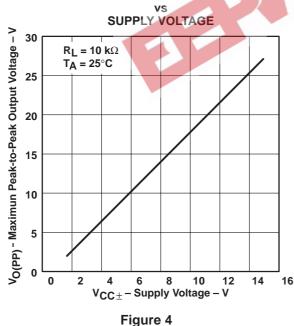
Figure 1. Unity-Gain Amplifier

TYPICAL CHARACTERISTICS[†]

INPUT BIAS CURRENT FREE-AIR TEMPERATURE 250 $V_{CC\pm} = \pm 15 \text{ V}$ 225 200 IB-Input Bias Current - mA 175 150 125 100 75 50 25 0 └ -75 125 -50 25 50 75 100 -25 0 T_A – Free-Air Temperature – $^{\circ}$ C

Figure 2

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE



INPUT BIAS CURRENT vs SUPPLY VOLTAGE

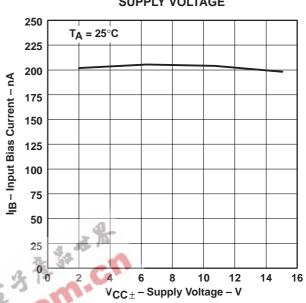


Figure 3

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE

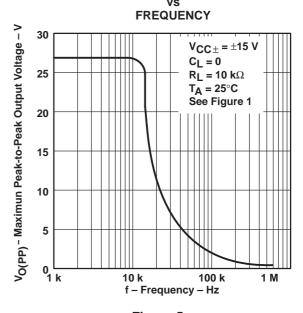


Figure 5

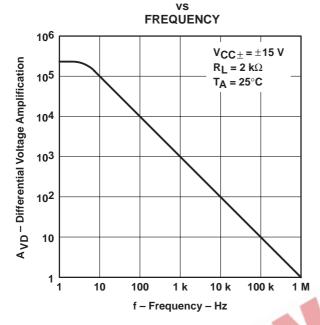
[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.



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TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION



VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

10 $V_{CC\pm} = \pm 15 \text{ V}$ $R_L = 2 \text{ k}\Omega$ $T_A = 25^{\circ}\text{C}$ See Figure 1

Figure 6

Figure 7

 $\textbf{t-Time}-\mu\textbf{s}$

20 30 40

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